Technical Data Data Sheet 3003, Rev. A

## 30CPQ050/30CPQ060 SCHOTTKY RECTIFIER

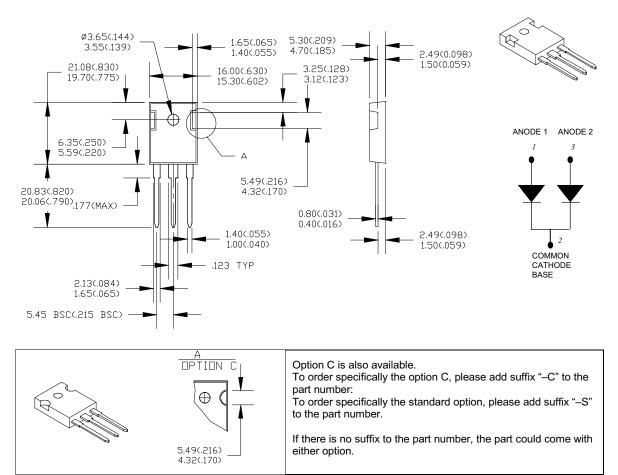
## **Applications:**

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

### Features:

- 150 °C T<sub>J</sub> operation
- Center tap TO-247AD package
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability

### Mechanical Dimensions: In Inches / mm



**TO-247AD** 

World Wide Web Site - http://www.sensitron.com
E-Mail Address - sales@sensitron.com



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# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	50(30CPQ050) 60(30CPQ060)	٧
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =112 °C, rectangular wave form	30	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	315	А
Non-Repetitive Avalanche Energy (per leg)	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L =11.5 mH	13	mJ
Repetitive Avalanche Current (per leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	1.50	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 15 A, Pulse, T <sub>J</sub> = 25 °C @ 30 A, Pulse, T <sub>J</sub> = 25 °C	0.60 0.80	V
	$V_{F2}$	@ 15 A, Pulse, T <sub>J</sub> = 125 °C @ 30 A, Pulse, T <sub>J</sub> = 125 °C	0.56 0.70	V
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.80	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	45	mA
Max. Junction Capacitance (per leg)	C <sub>T</sub>	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	720	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	7.5	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

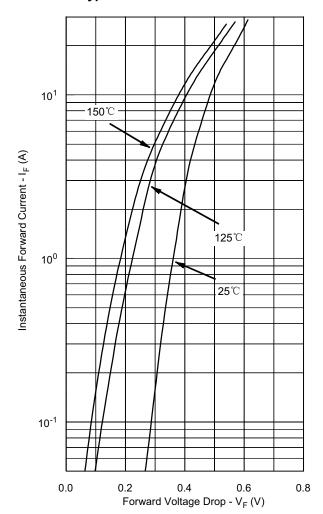
Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	TJ	-	-55 to +150	°C	
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	Ô	
Maximum Thermal		DC operation	2.20(per leg)	°C/W	
Resistance Junction to Case	$R_{\theta JC}$	DC operation	1.10(per device)	C/VV	
Maximum Thermal	R <sub>θCS</sub>	Mounting surface, smooth	0.24	°C/W	
Resistance, Case to Heat		and greased			
Sink					
Approximate Weight	wt	-	6	g	
Mounting Torque	т	-	6 (min)	Kg-cm	
	T <sub>M</sub>		12 (max)	ry-ciii	
Case Style	TO-247AD				

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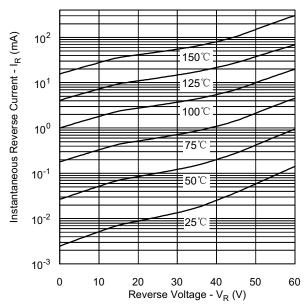
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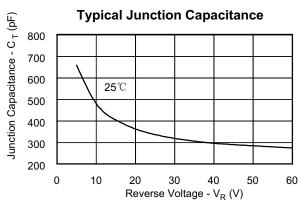
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## **Typical Forward Characteristics**



### **Typical Reverse Characteristics**





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